

	Typ	L #	Hits	Search T xt	DBs	Time Stamp
1	BRS	L1	83252	(ONO or (oxide adj nitride adj oxide))	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/06/28 15:42
2	BRS	L2	7934	(gate near2 (insulator or dielectride))	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/06/28 15:42
3	BRS	L3	188127 9	memory or CAM or (code near2 address) or RAM or SRAM or flash	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/06/28 15:44
4	BRS	L4	14	1 near8 2 same 3	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/06/28 15:44